SBOS282B − DECEMBER 2003 − REVISED FEBRUARY 2005

0.05μV/°C max, SINGLE-SUPPLY CMOS OPERATIONAL AMPLIFIERS Zer∅-Drift Series

FEATURES

- **LOW OFFSET VOLTAGE: 5μV (max)**
- **ZERO DRIFT: 0.05μV/°C max**
- **QUIESCENT CURRENT: 750μA (max)**
- **SINGLE-SUPPLY OPERATION**
- **LOW BIAS CURRENT: 200pA (max)**
- **SHUTDOWN**
- ***Micro*SIZE PACKAGES**
- **WIDE SUPPLY RANGE: 2.7V to 12V**

APPLICATIONS

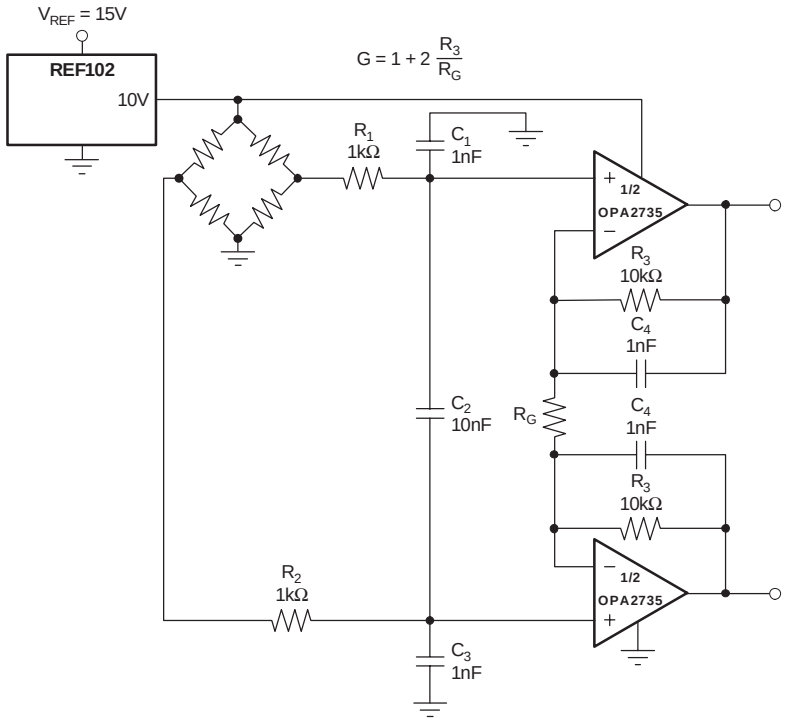
- **TRANSDUCER APPLICATIONS**
- **TEMPERATURE MEASUREMENTS**
- **ELECTRONIC SCALES**
- **MEDICAL INSTRUMENTATION**
- **BATTERY-POWERED INSTRUMENTS**
- **HANDHELD TEST EQUIPMENT**

DESCRIPTION

The OPA734 and OPA735 series of CMOS operational amplifiers use auto-zeroing techniques to simultaneously provide low offset voltage (5μV max) and near-zero drift over time and temperature. These miniature, high-precision, low quiescent current amplifiers offer high input impedance and rail-to-rail output swing within 50mV of the rails. Either single or bipolar supplies can be used in the range of +2.7V to +12V (±1.35V to ±6V). They are optimized for low-voltage, single-supply operation.

The OPA734 family includes a shutdown mode. Under logic control, the amplifiers can be switched from normal operation to a standby current that is 9μA (max) and the output placed in a high-impedance state.

The single version is available in the MicroSIZE SOT23-5 (SOT23-6 for shutdown version) and the SO-8 packages. The dual version is available in the MSOP-8 and SO-8 packages (MSOP-10 only for the shutdown version). All versions are specified for operation from −40°C to +85°C.



ABSOLUTE MAXIMUM RATINGS(1)

Supply Voltage	+13.2V
Signal Input Terminals, Voltage(2)	(V−) − 0.5V to (V+) + 0.5V
Current(2)	±10mA
Output Short Circuit(3)	Continuous
Operating Temperature	−40°C to +150°C
Storage Temperature	−65°C to +150°C
Junction Temperature	+150°C
Lead Temperature (soldering, 10s)	+300°C
ESD Rating (Human Body Model), OPA734	1000V
ESD Rating (Human Body Model), OPA735, OPA2734, OPA2735	2000V

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
(2) Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5V beyond the supply rails should be current limited to 10mA or less.
(3) Short-circuit to ground, one amplifier per package.

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGE/ORDERING INFORMATION(1)

PRODUCT	PACKAGE-LEAD	PACKAGE DESIGNATOR	SPECIFIED TEMPERATURE RANGE	PACKAGE MARKING	ORDERING NUMBER	TRANSPORT MEDIA, QUANTITY
Shutdown Version						
OPA734	SOT23-6	DBV	−40°C to +85°C	NSB	OPA734AIDBVT	Tape and Reel, 250
〃	〃	〃	〃	〃	OPA734AIDBVR	Tape and Reel, 3000
OPA734	SO-8	D	−40°C to +85°C	OPA734A	OPA734AID	Rails, 100
〃	〃	〃	〃	〃	OPA734AIDR	Tape and Reel, 2500
OPA2734	MSOP-10	DGS	−40°C to +85°C	BGO	OPA2734AIDGST	Tape and Reel, 250
〃	〃	〃	〃	〃	OPA2734AIDGSR	Tape and Reel, 2500
Non-Shutdown Version						
OPA735	SOT23-5	DBV	−40°C to +85°C	NSC	OPA735AIDBVT	Tape and Reel, 250
〃	〃	〃	〃	〃	OPA735AIDBVR	Tape and Reel, 3000
OPA735	SO-8	D	−40°C to +85°C	OPA735A	OPA735AID	Rails, 100
〃	〃	〃	〃	〃	OPA735AIDR	Tape and Reel, 2500
OPA2735	SO-8	D	−40°C to +85°C	OPA2735A	OPA2735AID	Rails, 100
〃	〃	〃	〃	〃	OPA2735AIDR	Tape and Reel, 2500
OPA2735	MSOP-8	DGK	−40°C to +85°C	BGN	OPA2735AIDGKT	Tape and Reel, 250
〃	〃	〃	〃	〃	OPA2735AIDGKR	Tape and Reel, 2500

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

ELECTRICAL CHARACTERISTICS: V_S = ±5V (V_S = +10V)

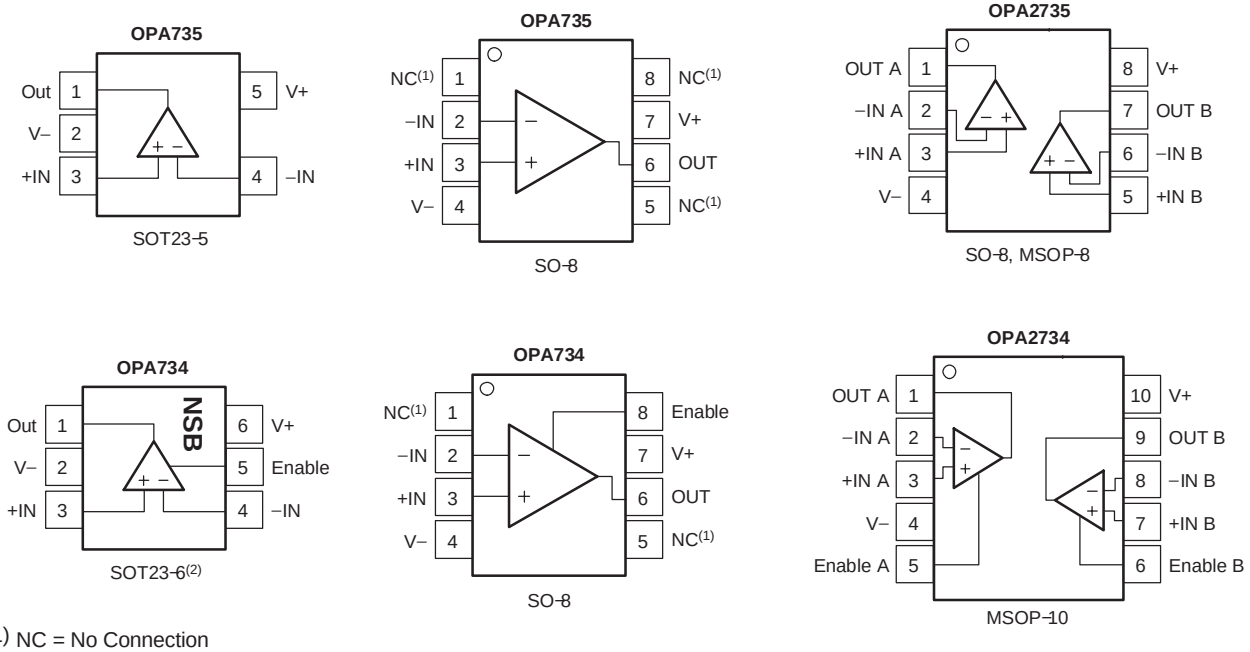
Boldface limits apply over the specified temperature range, **T_A = −40°C to +85°C.**

At T_A = +25°C, R_L = 10kΩ connected to V_S/2, and V_{OUT} = V_S/2, unless otherwise noted.

PARAMETER		CONDITIONS	OPA734, OPA2734, OPA735, OPA2735 MIN	TYP	MAX	UNIT
OFFSET VOLTAGE						
Input Offset Voltage	V_{OS}			1	5	µV
vs Temperature	**dV_{OS}/dT**			**0.01**	**0.05**	**µV/°C**
vs Power Supply	**PSRR**	**V_S = 2.7V to 12V, V_{CM} = 0V**		**0.2**	**1.8**	**µV/V**
Long-Term Stability				Note (1)		
Channel Separation, dc				0.1		µV/V
INPUT BIAS CURRENT						
Input Bias Current	I_B	V_{CM} = V_S/2		±100	±200	pA
over Temperature				**See Typical Characteristics**		**pA**
Input Offset Current	I_{OS}	V_{CM} = V_S/2		±200	±300	pA
NOISE						
Input Voltage Noise, f = 0.01Hz to 1Hz	e_n			0.8		μV_{PP}
Input Voltage Noise, f = 0.1Hz to 10Hz	e_n			2.5		μV_{PP}
Input Voltage Noise Density, f = 1kHz	e_n			135		nV/√Hz
Input Current Noise Density, f = 1kHz	i_n			40		fA/√Hz
INPUT VOLTAGE RANGE						
Common-Mode Voltage Range	**V_{CM}**		**(V−) − 0.1**		**(V+) − 1.5**	**V**
Common-Mode Rejection Ratio	**CMRR**	**(V−) − 0.1V < V_{CM} < (V+) − 1.5V**	**115**	**130**		**dB**
INPUT CAPACITANCE						
Differential				2		pF
Common-Mode				10		pF
OPEN-LOOP GAIN						
Open-Loop Voltage Gain	**A_{OL}**	**(V−) + 100mV < V_O < (V+) − 100mV**	**115**	**130**		**dB**
FREQUENCY RESPONSE						
Gain-Bandwidth Product	GBW			1.6		MHz
Slew Rate	SR	G = +1		1.5		V/µs
OUTPUT						
Voltage Output Swing from Rail		**R_L = 10kΩ**		**20**	**50**	**mV**
Short-Circuit Current	I_{SC}			±20		mA
Open-Loop Output Impedance		f = 1MHz, I_O = 0		125		Ω
Capacitive Load Drive	C_{LOAD}			See Typical Characteristics		
ENABLE/SHUTDOWN						
t_{OFF}				1.5		µs
t_{ON}(2)				150		µs
V_L (amplifier is shutdown)			V−		(V−) + 0.8	V
V_H (amplifier is active)			(V−) + 2		V+	V
I_{QSD} (per amplifier)				4	9	µA
Input Bias Current of Enable Pin				3		µA
POWER SUPPLY						
Operating Voltage Range	V_S			2.7 to 12 (±1.35 to ±6)		V
Quiescent Current (per amplifier)	**I_Q**	**I_O = 0**		**0.6**	**0.75**	**mA**
TEMPERATURE RANGE						
Specified Range			−40		+85	°C
Operating Range			−40		+150	°C
Storage Range			−65		+150	°C
Thermal Resistance	θ_{JA}					°C/W
SOT23-5, SOT23-6				200		°C/W
MSOP-8, MSOP-10, SO-8				150		°C/W

(1) 300-hour life test at 150°C demonstrated randomly distributed variation in the range of measurement limits—approximately 1µV.
(2) Device requires one complete auto-zero cycle to return to V_{OS} accuracy.

PIN CONFIGURATIONS

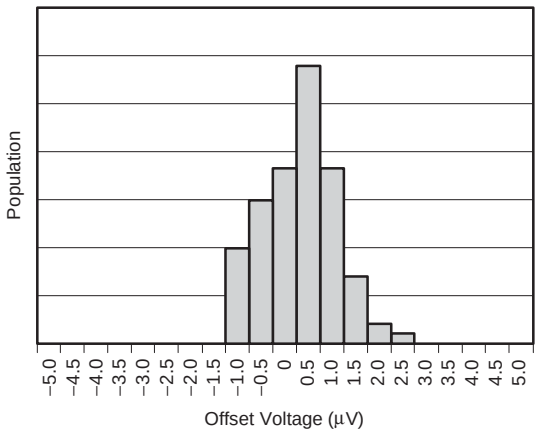


(1) NC = No Connection
(2) Pin 1 of the SOT23-6 is determined by orienting the package marking as shown in the diagram.

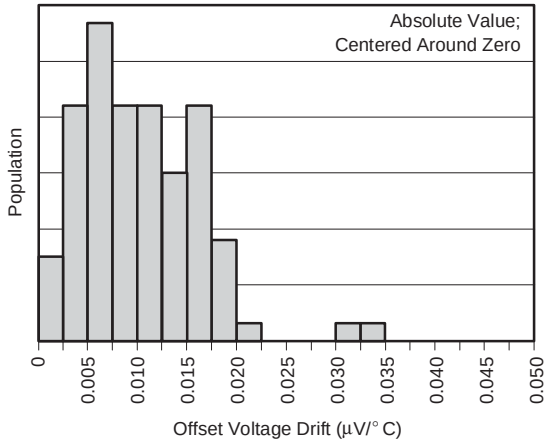
TYPICAL CHARACTERISTICS

At T_A = +25°C, V_S = ±5V (same as +10V).

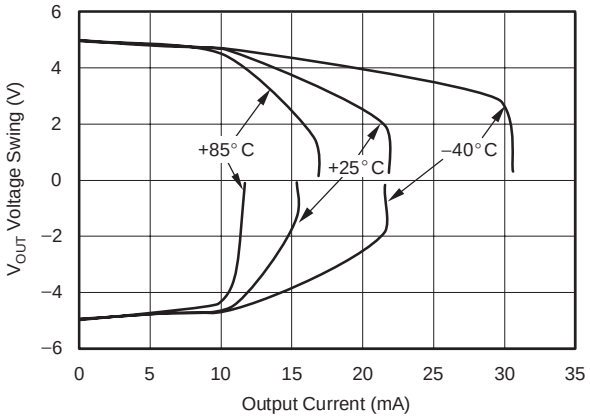
OUTPUT VOLTAGE PRODUCTION DISTRIBUTION



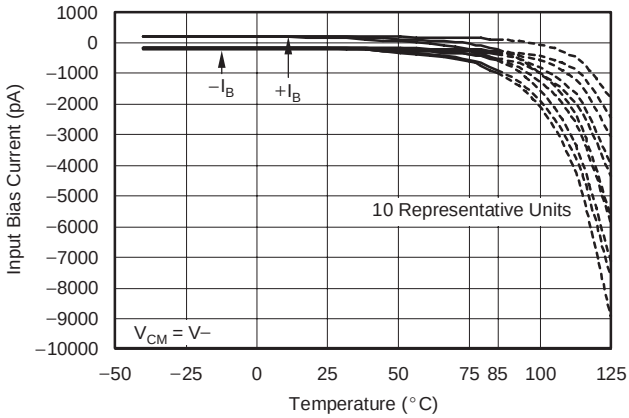
OUTPUT VOLTAGE DRIFT PRODUCTION DISTRIBUTION



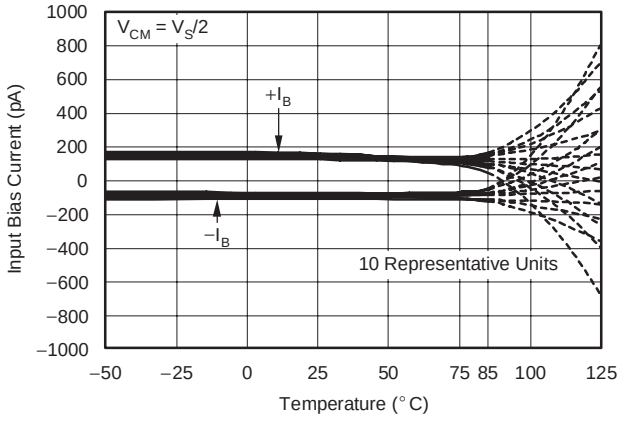
OUTPUT VOLTAGE SWING TO RAIL
vs OUTPUT CURRENT



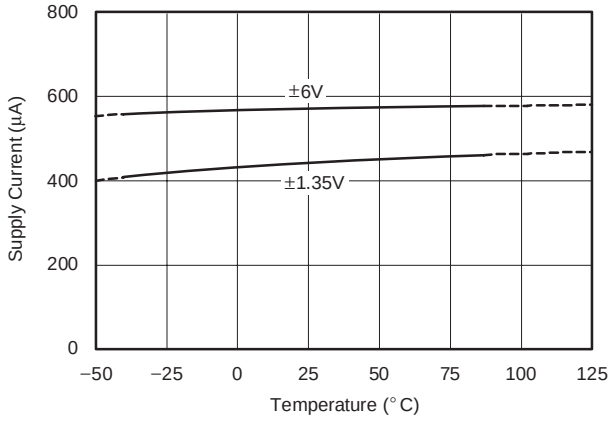
INPUT BIAS CURRENT vs TEMPERATURE



INPUT BIAS CURRENT vs TEMPERATURE



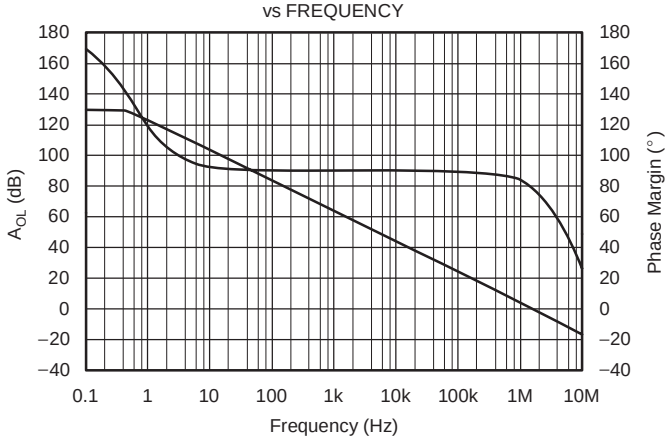
SUPPLY CURRENT vs TEMPERATURE



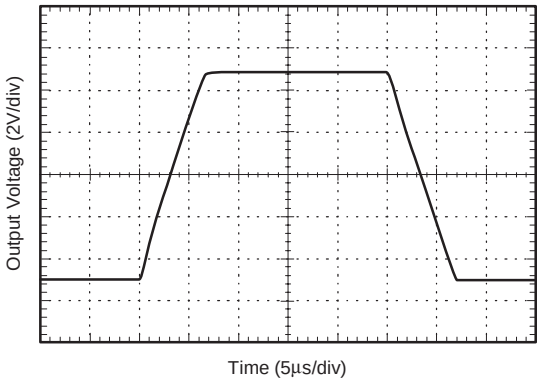
TYPICAL CHARACTERISTICS (continued)

At T_A = +25°C, V_S = ±5V (same as +10V).

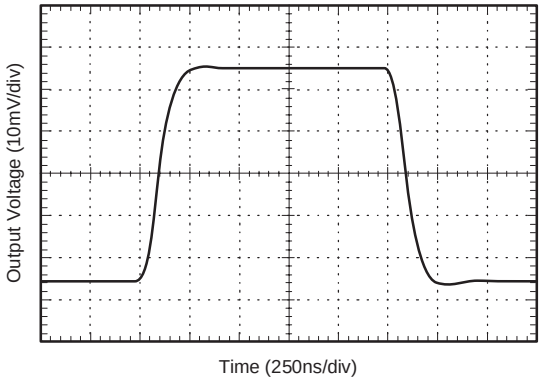
OPEN−LOOP GAIN AND PHASE MARGIN vs FREQUENCY



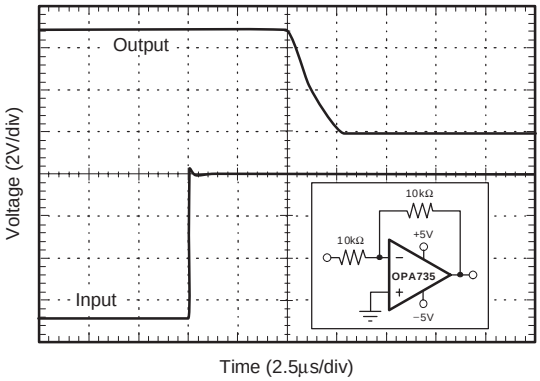
LARGE−SIGNAL RESPONSE



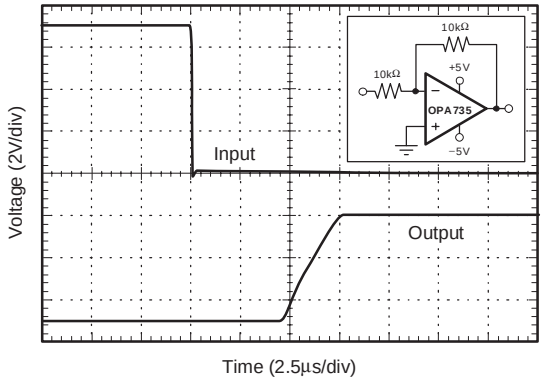
SMALL−SIGNAL RESPONSE



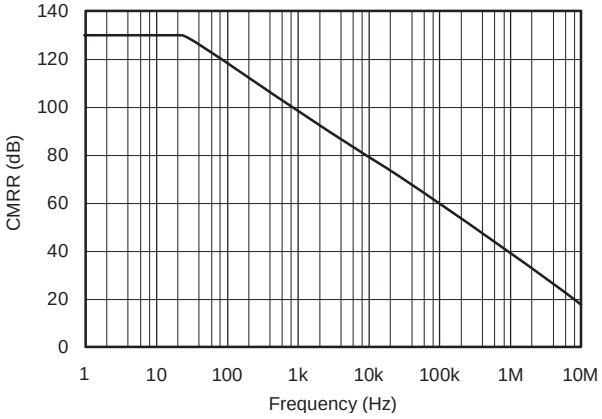
POSITIVE OVERVOLTAGE RECOVERY



NEGATIVE OVERVOLTAGE RECOVERY



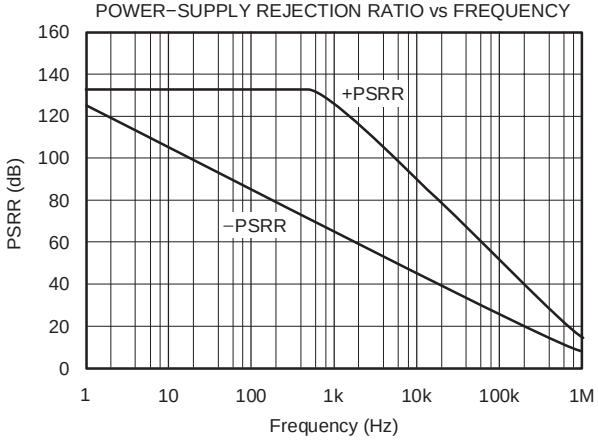
COMMON−MODE REJECTION RATIO vs FREQUENCY



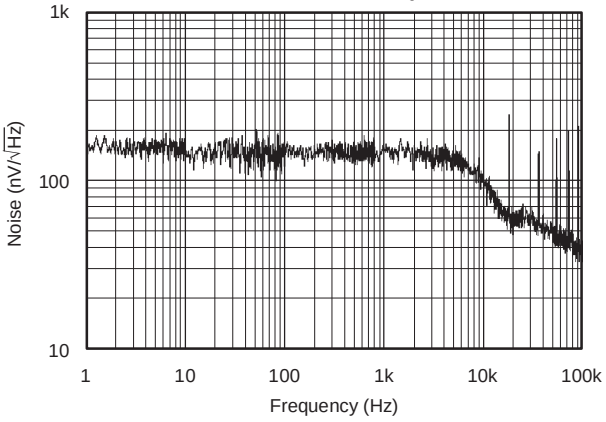
TYPICAL CHARACTERISTICS (continued)

At T_A = +25°C, V_S = ±5V (same as +10V).

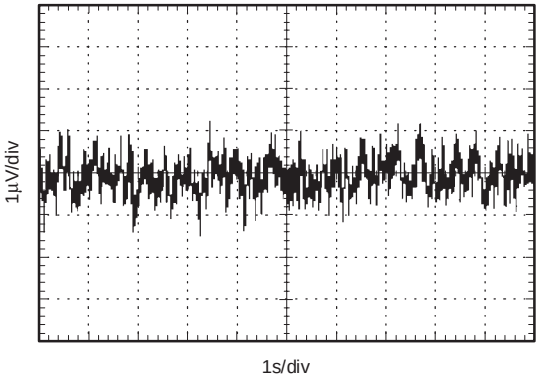
POWER−SUPPLY REJECTION RATIO vs FREQUENCY



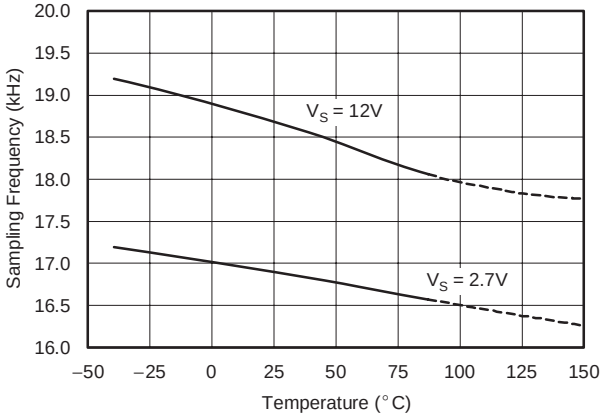
VOLTAGE NOISE vs FREQUENCY



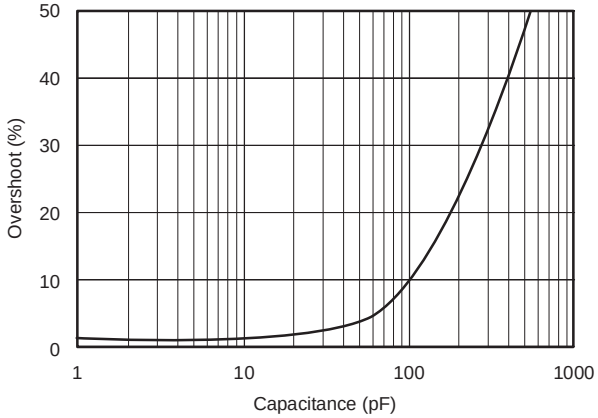
0.1Hz TO 10Hz NOISE



SAMPLING FREQUENCY vs TEMPERATURE



SMALL−SIGNAL OVERSHOOT vs CAPACITIVE LOAD



APPLICATIONS INFORMATION

The OPA734 and OPA735 series of op amps are unity-gain stable and free from unexpected output phase reversal. They use auto-zeroing techniques to provide low offset voltage and demonstrate very low drift over time and temperature.

Good layout practice mandates the use of a 0.1µF capacitor placed closely across the supply pins.

For lowest offset voltage and precision performance, circuit layout and mechanical conditions should be optimized. Avoid temperature gradients that create thermoelectric (Seebeck) effects in thermocouple junctions formed from connecting dissimilar conductors. These thermally-generated potentials can be made to cancel by assuring that they are equal on both input terminals:

1. Use low thermoelectric-coefficient connections (avoid dissimilar metals).
2. Thermally isolate components from power supplies or other heat sources.
3. Shield op amp and input circuitry from air currents such as cooling fans.

Following these guidelines will reduce the likelihood of junctions being at different temperatures, which can cause thermoelectric voltages of 0.1µV/°C or higher, depending on the materials used.

OPERATING VOLTAGE

The OPA734 and OPA735 op amp family operates with a power-supply range of +2.7V to +12V (±1.35V to ±6V). Supply voltages higher than +13.2V (absolute maximum) can permanently damage the amplifier. Parameters that vary over supply voltage or temperature are shown in the Typical Characteristics section of this data sheet.

OPA734 ENABLE FUNCTION

The enable/shutdown digital input is referenced to the V− supply voltage of the op amp. A logic HIGH enables the op amp. A valid logic HIGH is defined as > (V−) + 2V. The valid logic HIGH signal can be up to the positive supply, independent of the negative power supply voltage. A valid logic LOW is defined as < 0.8V above the V− supply pin. If dual or split power supplies are used, be sure that logic input signals are properly referred to the negative supply voltage. The Enable pin is connected to internal pull-up circuitry and will enable the device if this pin is left open circuit.

The logic input is a CMOS input. Separate logic inputs are provided for each op amp on the dual version. For battery-operated applications, this feature can be used to greatly reduce the average current and extend battery life.

The enable time is 150µs, which includes one full auto-zero cycle required by the amplifier to return to V_{OS} accuracy. Prior to returning to full accuracy, the amplifier may function properly, but with unspecified offset voltage.

Disable time is 1.5µs. When disabled, the output assumes a high-impedance state. The disable state allows the OPA734 to be operated as a gated amplifier, or to have the output multiplexed onto a common analog output bus.

INPUT VOLTAGE

The input common-mode range extends from (V−) − 0.1V to (V+) − 1.5V. For normal operation, the inputs must be limited to this range. The common-mode rejection ratio is only valid within the specified input common-mode range. A lower supply voltage results in lower input common-mode range; therefore, attention to these values must be given when selecting the input bias voltage. For example, when operating on a single 3V power supply, common-mode range is from 0.1V below ground to half the power-supply voltage.

Normally, input bias current is approximately 100pA; however, input voltages exceeding the power supplies can cause excessive current to flow in or out of the input pins. Momentary voltages greater than the power supply can be tolerated if the input current is limited to 10mA. This is easily accomplished with an input resistor, as shown in Figure 1.

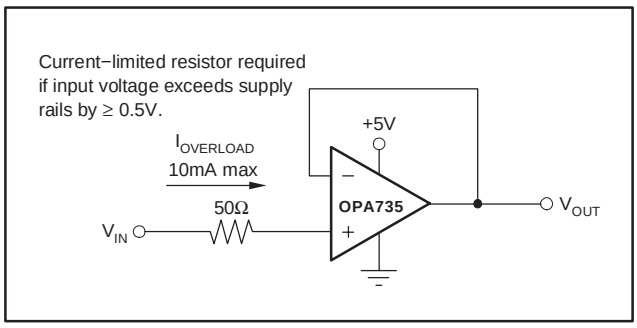


Figure 1. Input Current Protection

INTERNAL OFFSET CORRECTION

The OPA734 and OPA735 series of op amps use an auto-zero topology with a time-continuous 1.6MHz op amp in the signal path. This amplifier is zero-corrected every 100µs using a proprietary technique. Upon power-up, the amplifier requires one full auto-zero cycle of approximately 100µs in addition to the start-up time for the bias circuitry to achieve specified V_{OS} accuracy. Prior to this time, the amplifier may function properly but with unspecified offset voltage.

Low-gain (< 20) operation demands that the auto-zero circuitry correct for common-mode rejection errors of the main amplifier. Because these errors can be larger than 0.1% of a full-scale input step change, one calibration cycle (100µs) can be required to achieve full accuracy.

The term *clock feedthrough* describes the presence of the clock frequency in the output spectrum. In auto-zeroed op amps, clock feedthrough may result from the settling of the internal sampling capacitor, or from the small amount of charge injection that occurs during the sample-and-hold of the op amp offset voltage. Feedthrough can be minimized by keeping the source impedance relatively low (< 1kΩ) and matching the source impedance on both input terminals. If the source resistance is high (> 1kΩ) feedthrough can generally be reduced with a capacitor of 1nF or greater in parallel with the source or feedback resistors. See the circuit application examples.

LAYOUT GUIDELINES

Attention to good layout practices is always recommended. Keep traces short. When possible, use a PCB ground plane with surface-mount components placed as close to the device pins as possible. Place a 0.1µF capacitor closely across the supply pins. These guidelines should be applied throughout the analog circuit to improve performance and provide benefits such as reducing the electromagnetic-interference (EMI) susceptibility.

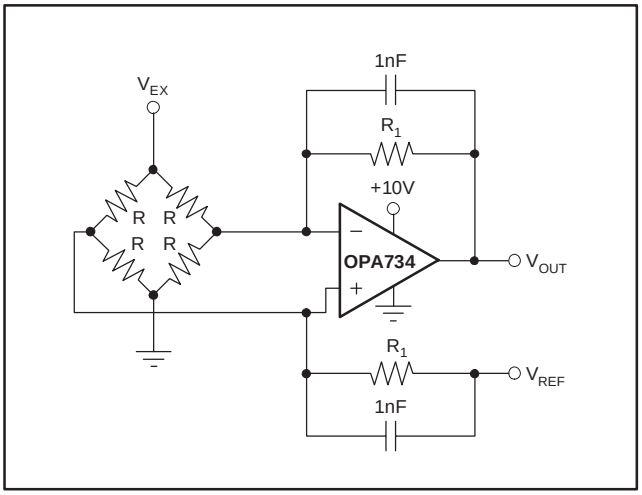


Figure 2. Single Op Amp Bridge Amplifier Circuit

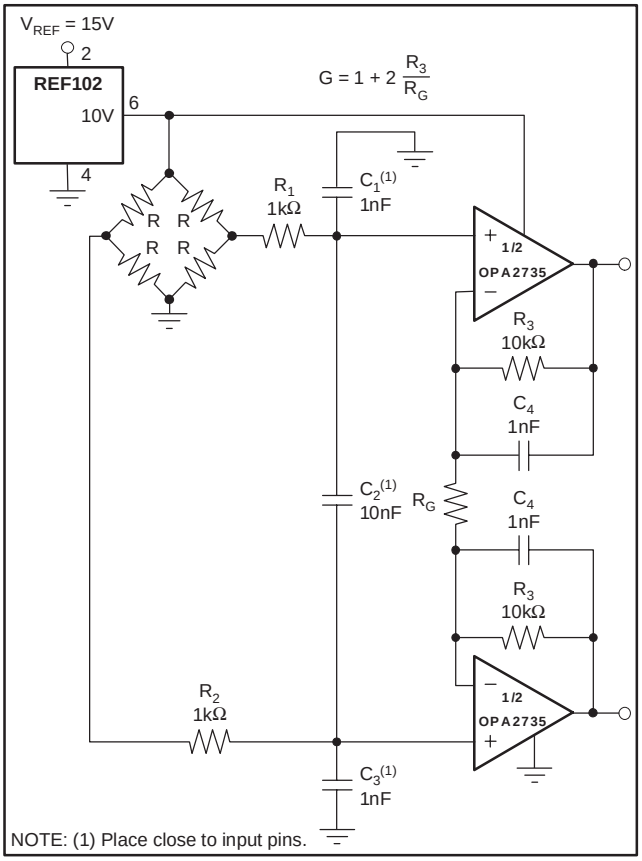
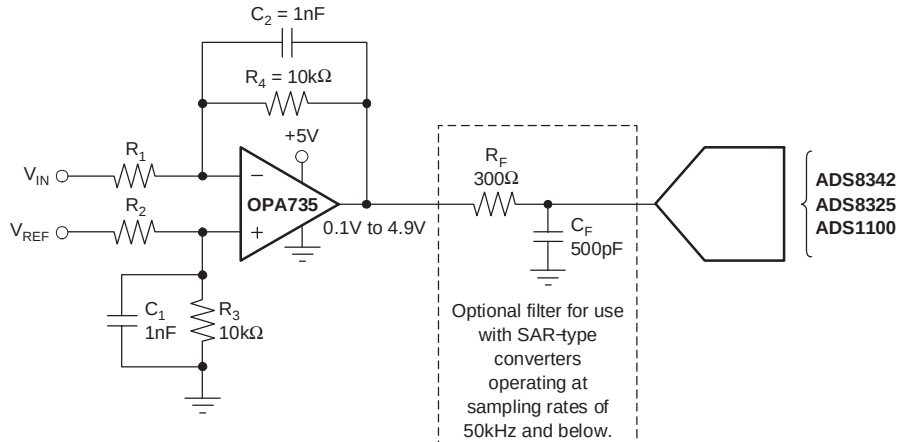
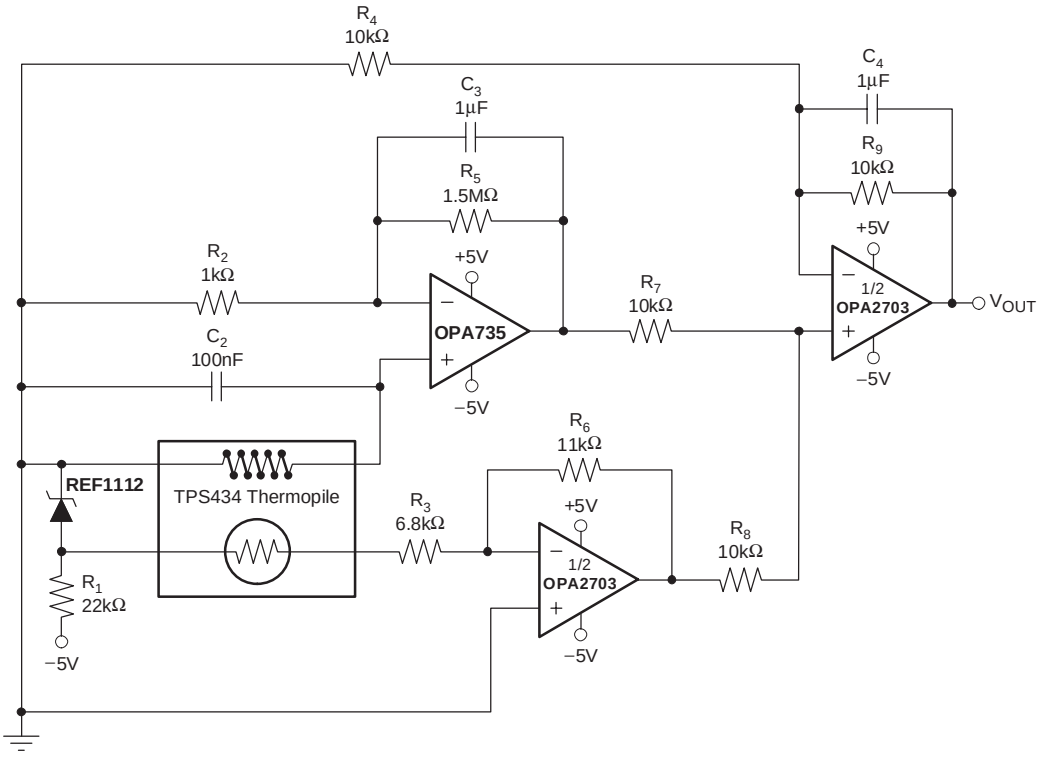


Figure 3. Differential Output Bridge Amplifier



V_{IN}	V_{REF}	R_1	R_2
±10V	5V	42.2kΩ	14.7kΩ
±5V	5V	20.8kΩ	19.6kΩ
0V to 10V	5V	20.8kΩ	5.11kΩ
0V to 5V	5V	10.5kΩ	10kΩ

Figure 4. Driving ADC



NOTE: The TPS434, by Perkin Elmer Optoelectronics, is a thermopile detector with integrated thermistor for cold-junction reference.

Figure 5. Thermopile Non-Contact Surface Temperature Measurement

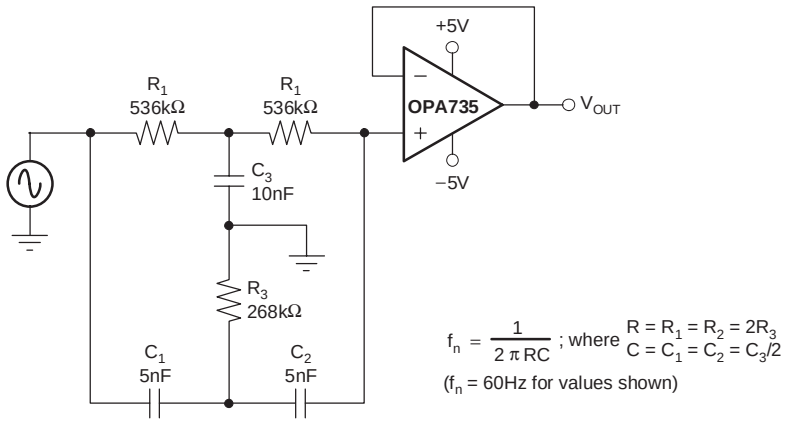
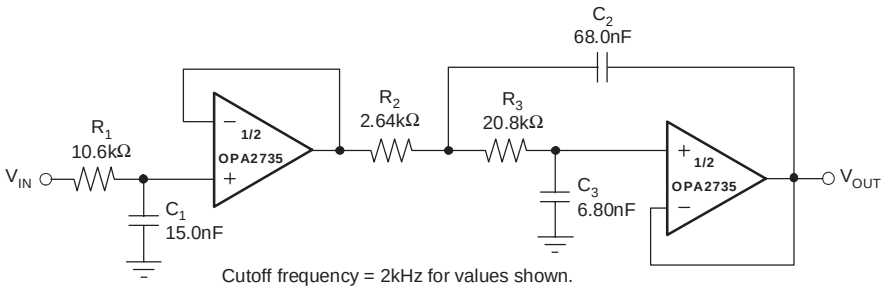
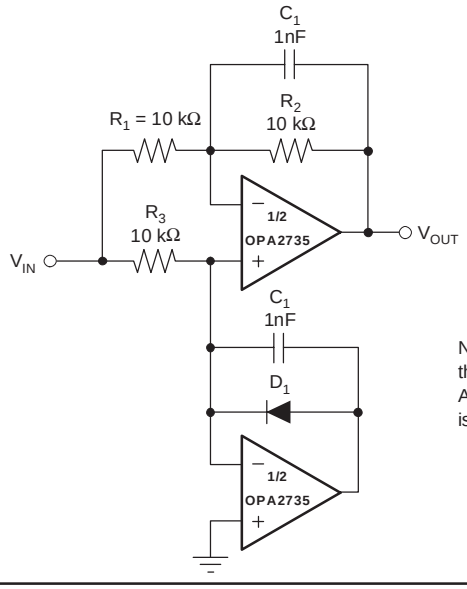


Figure 6. Twin-T Notch Filter



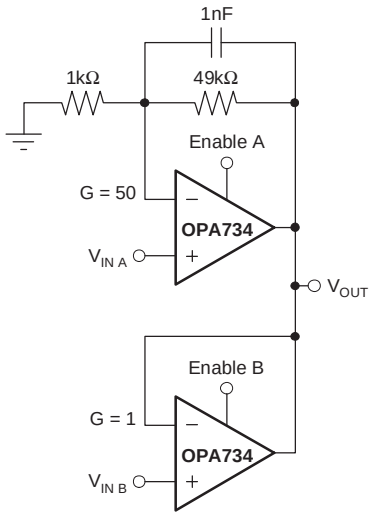
NOTE: FilterPro is a low-pass filter design program available for download at no cost from TI's web site (www.ti.com). The program can be used to easily determine component values for other cutoff frequencies or filter types.

Figure 7. High DC Accuracy, 3-Pole Low-Pass Filter



NOTE: Dynamic range of the circuit is not reduced by the diode voltage drop since the diode is not in the signal path. Application Bulletin *Precision Absolute Value Circuits* (SBOA068) is available at www.ti.com and provides further information about rectifier circuits.

Figure 8. Precision Full-Wave Rectifier with Full Dynamic Range



Enable inputs are CMOS logic compatible.

Figure 9. High-Precision 2-Input MUX for Programmable Gain

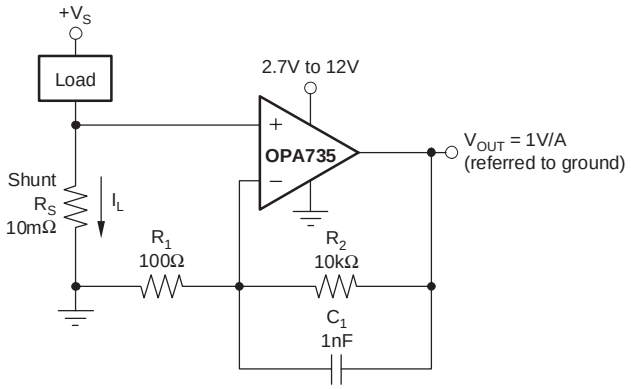


Figure 10. Low-Side Power-Supply Current Sensing

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
OPA2734AIDGSR	Active	Production	VSSOP (DGS) | 10	2500 | LARGE T&R	Yes	Call TI | Nipdauag	Level-2-260C-1 YEAR	-40 to 85	BGO
OPA2734AIDGSR.B	Active	Production	VSSOP (DGS) | 10	2500 | LARGE T&R	Yes	Call TI	Level-2-260C-1 YEAR	-40 to 85	BGO
OPA2734AIDGST	Active	Production	VSSOP (DGS) | 10	250 | SMALL T&R	Yes	Call TI | Nipdauag	Level-2-260C-1 YEAR	-40 to 85	BGO
OPA2734AIDGST.B	Active	Production	VSSOP (DGS) | 10	250 | SMALL T&R	Yes	Call TI	Level-2-260C-1 YEAR	-40 to 85	BGO
OPA2735AID	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 2735A
OPA2735AID.B	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 2735A
OPA2735AIDG4	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 2735A
OPA2735AIDGKR	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	Call TI | Sn | Nipdauag | Nipdau	Level-2-260C-1 YEAR	-40 to 85	BGN
OPA2735AIDGKR.B	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	BGN
OPA2735AIDGKT	Active	Production	VSSOP (DGK) | 8	250 | SMALL T&R	Yes	Call TI | Sn | Nipdauag | Nipdau	Level-2-260C-1 YEAR	-40 to 85	BGN
OPA2735AIDGKT.B	Active	Production	VSSOP (DGK) | 8	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	BGN
OPA2735AIDR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 2735A
OPA2735AIDR.B	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 2735A
OPA2735AIDRG4	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 2735A
OPA2735AIDRG4.B	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 2735A
OPA734AID	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 734A
OPA734AID.B	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 734A
OPA734AIDBVR	Active	Production	SOT-23 (DBV) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	NSB
OPA734AIDBVR.B	Active	Production	SOT-23 (DBV) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	NSB
OPA734AIDBVT	Active	Production	SOT-23 (DBV) | 6	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	NSB
OPA734AIDBVT.B	Active	Production	SOT-23 (DBV) | 6	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	NSB

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
OPA734AIDBVTG4	Active	Production	SOT-23 (DBV) | 6	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	NSB
OPA734AIDBVTG4.B	Active	Production	SOT-23 (DBV) | 6	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	NSB
OPA735AID	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 735A
OPA735AID.B	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 735A
OPA735AIDBVR	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	NSC
OPA735AIDBVR.B	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	NSC
OPA735AIDBVRG4	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	NSC
OPA735AIDBVT	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	NSC
OPA735AIDBVT.B	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	NSC
OPA735AIDBVTG4	Active	Production	SOT-23 (DBV) | 5	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	NSC
OPA735AIDG4	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 735A
OPA735AIDG4.B	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 735A
OPA735AIDR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 735A
OPA735AIDR.B	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 735A

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

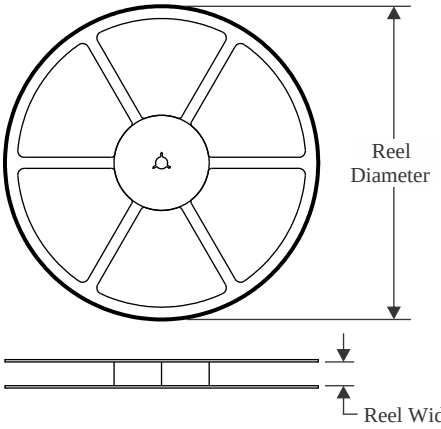
(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

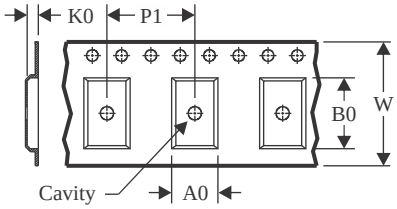
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

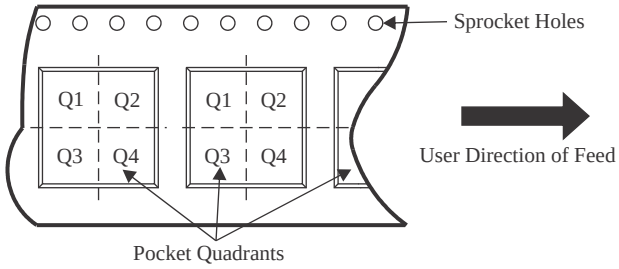


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

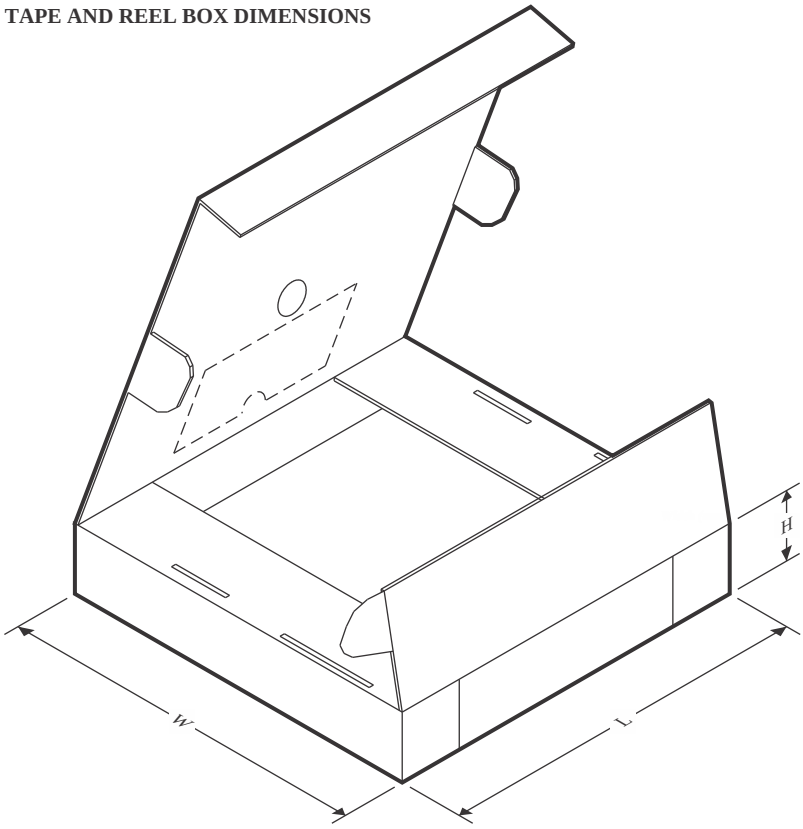
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA2735AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA2735AIDRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA734AIDBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
OPA734AIDBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
OPA734AIDBVTG4	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
OPA735AIDBVR	SOT-23	DBV	5	3000	178.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
OPA735AIDBVT	SOT-23	DBV	5	250	178.0	8.4	3.3	3.2	1.4	4.0	8.0	Q3
OPA735AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

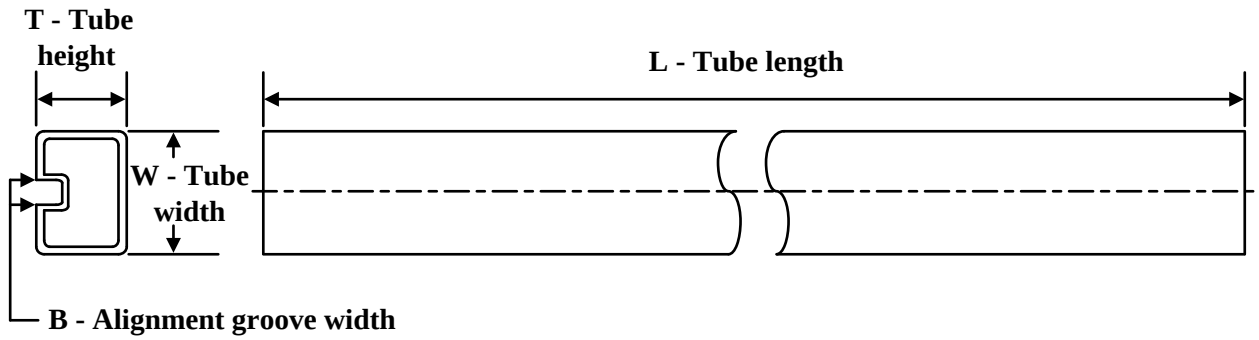
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA2735AIDR	SOIC	D	8	2500	353.0	353.0	32.0
OPA2735AIDRG4	SOIC	D	8	2500	353.0	353.0	32.0
OPA734AIDBVR	SOT-23	DBV	6	3000	445.0	220.0	345.0
OPA734AIDBVT	SOT-23	DBV	6	250	445.0	220.0	345.0
OPA734AIDBVTG4	SOT-23	DBV	6	250	445.0	220.0	345.0
OPA735AIDBVR	SOT-23	DBV	5	3000	565.0	140.0	75.0
OPA735AIDBVT	SOT-23	DBV	5	250	565.0	140.0	75.0
OPA735AIDR	SOIC	D	8	2500	353.0	353.0	32.0

TUBE



*All dimensions are nominal

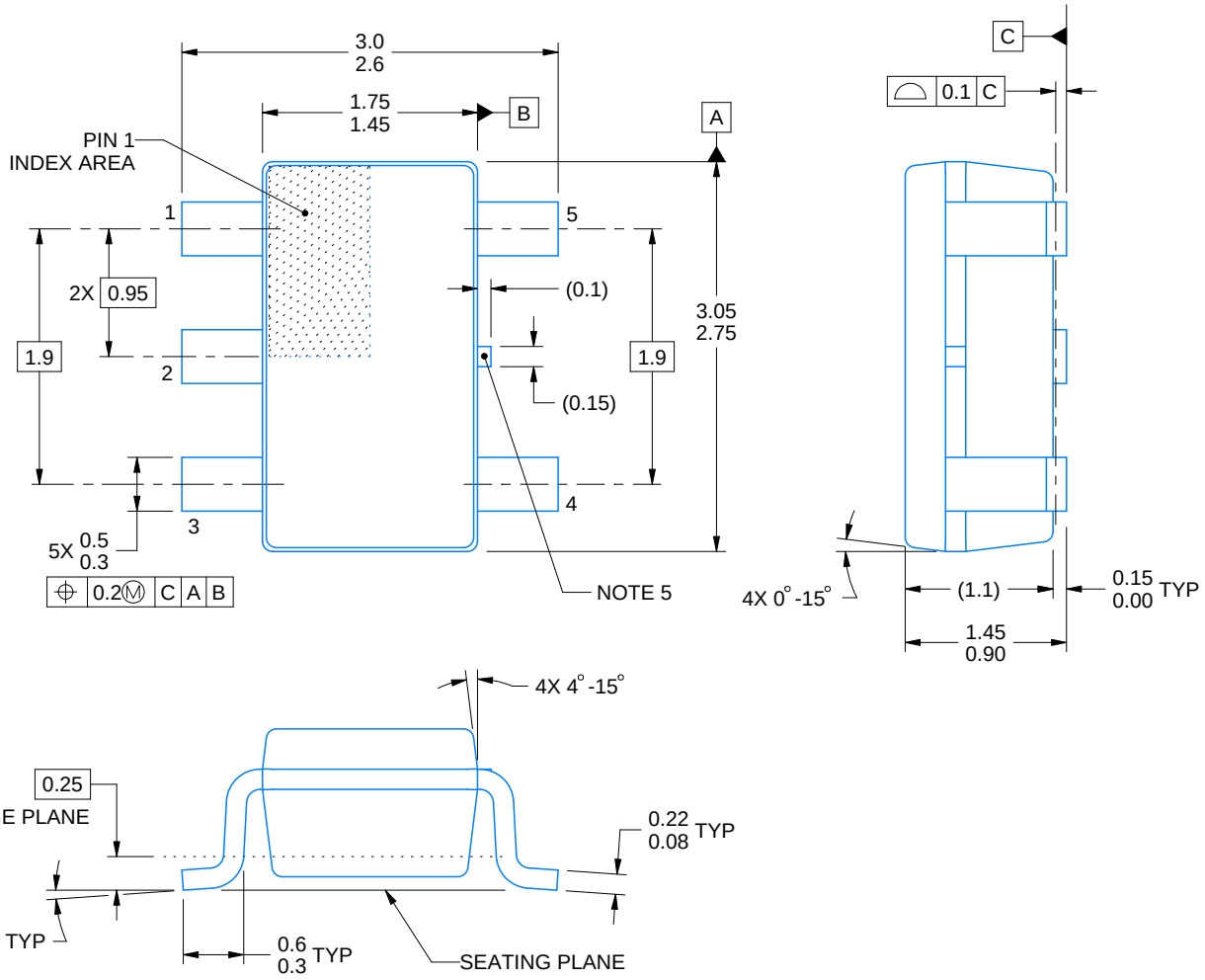
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
OPA2735AID	D	SOIC	8	75	506.6	8	3940	4.32
OPA2735AID.B	D	SOIC	8	75	506.6	8	3940	4.32
OPA2735AIDG4	D	SOIC	8	75	506.6	8	3940	4.32
OPA734AID	D	SOIC	8	75	506.6	8	3940	4.32
OPA734AID.B	D	SOIC	8	75	506.6	8	3940	4.32
OPA735AID	D	SOIC	8	75	506.6	8	3940	4.32
OPA735AID.B	D	SOIC	8	75	506.6	8	3940	4.32
OPA735AIDG4	D	SOIC	8	75	506.6	8	3940	4.32
OPA735AIDG4.B	D	SOIC	8	75	506.6	8	3940	4.32

PACKAGE OUTLINE

DBV0005A

SOT-23 - 1.45 mm max height

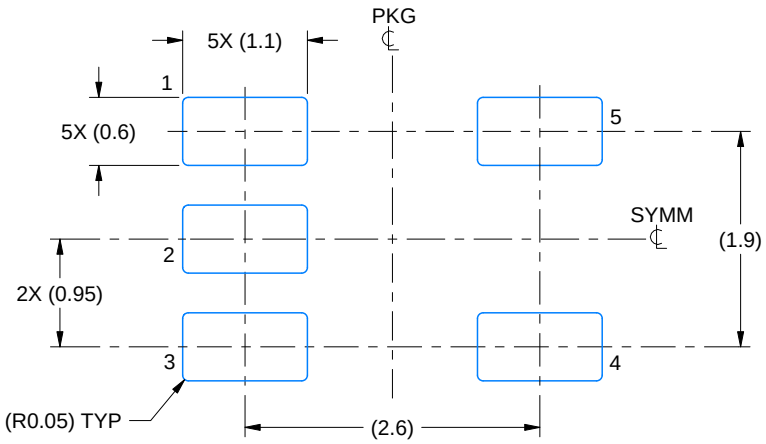
SMALL OUTLINE TRANSISTOR



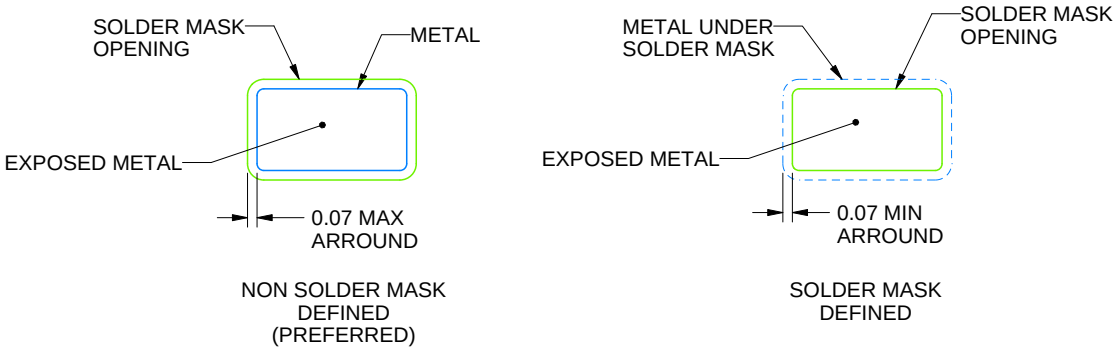
4214839/K 08/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Refernce JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

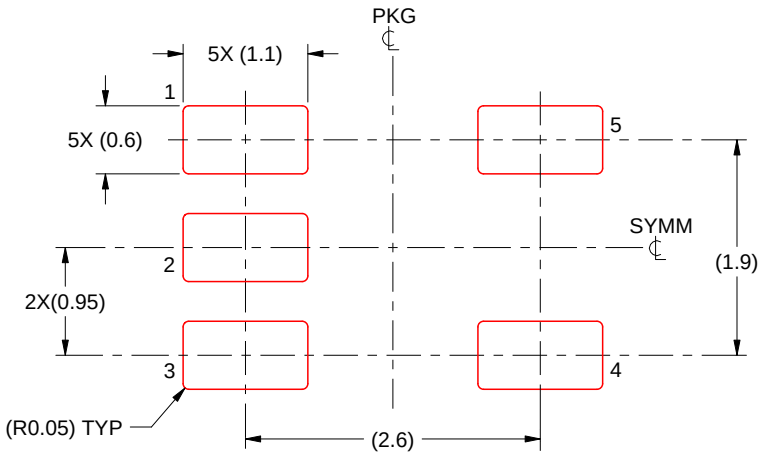


SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

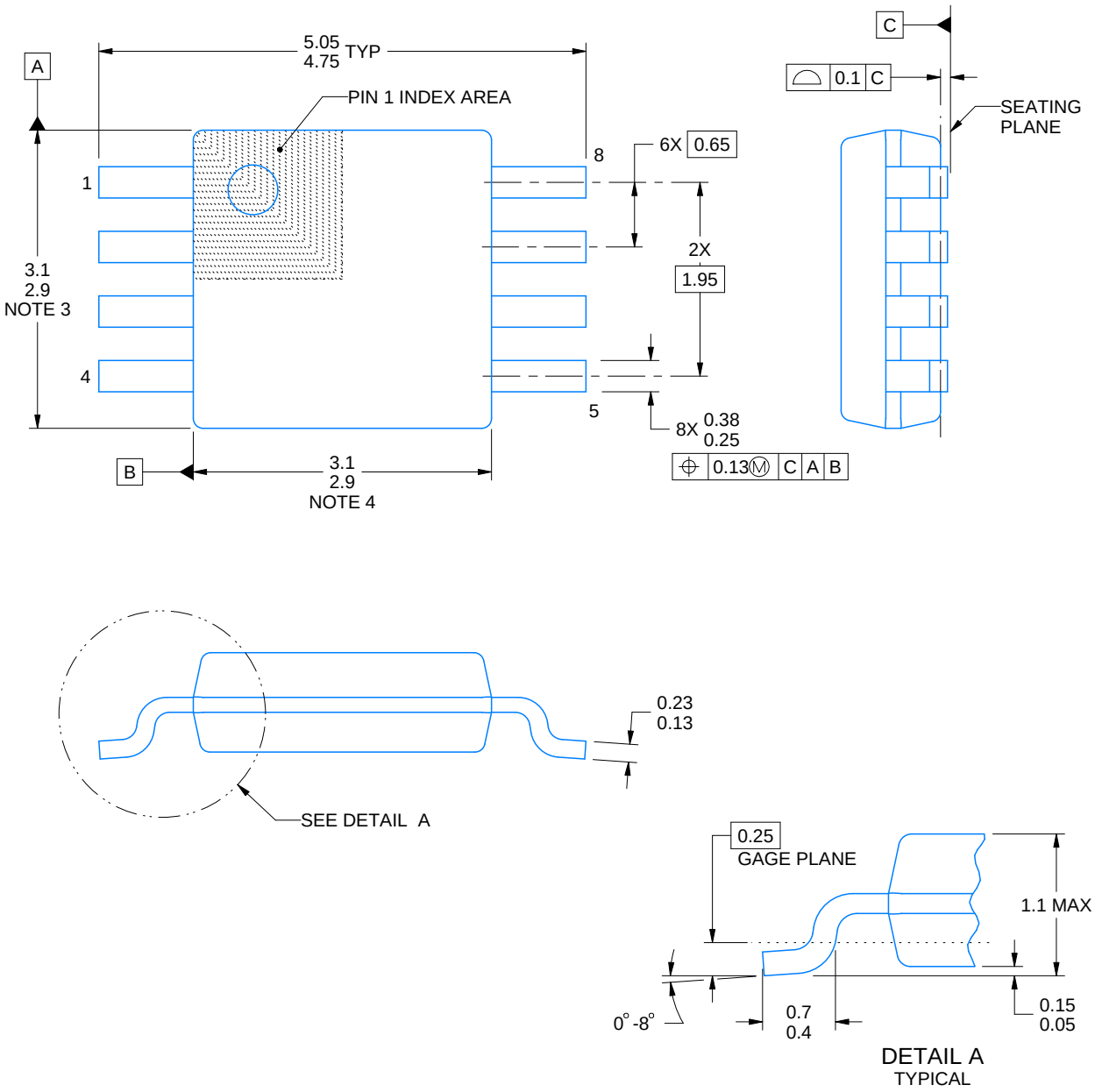
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

PACKAGE OUTLINE

DGK0008A

VSSOP - 1.1 mm max height

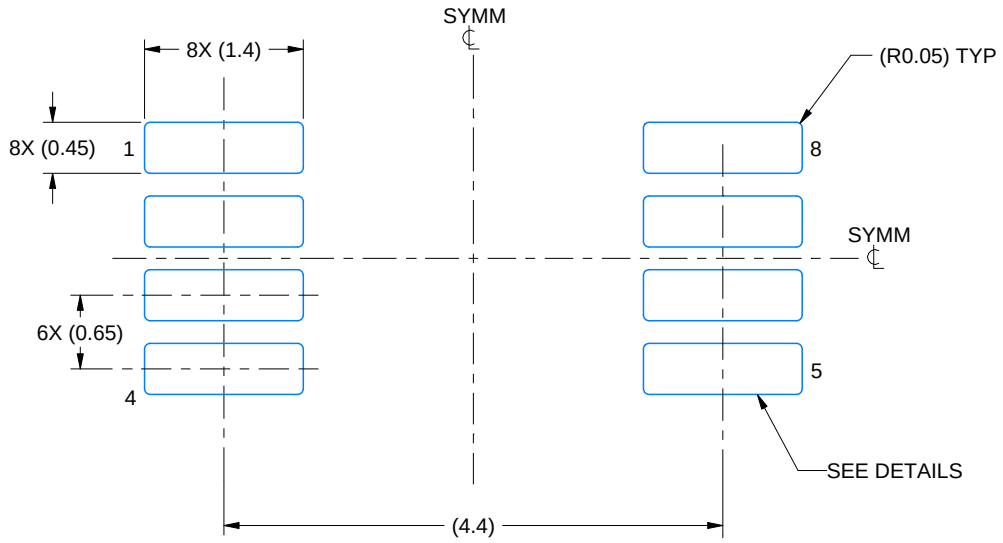
SMALL OUTLINE PACKAGE



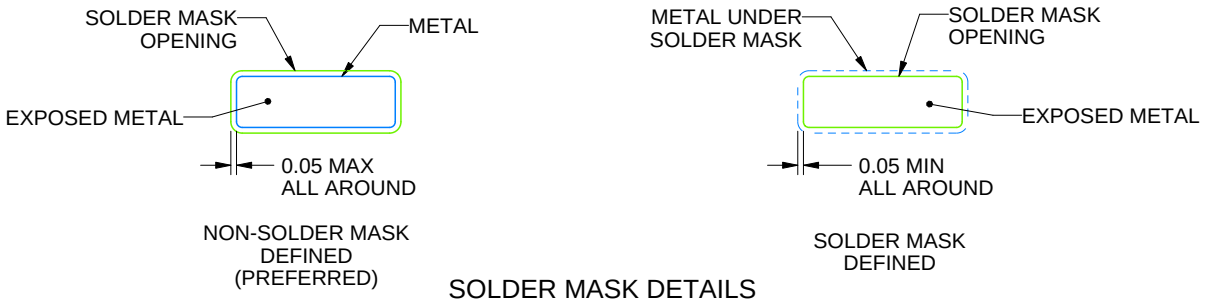
PowerPAD is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X

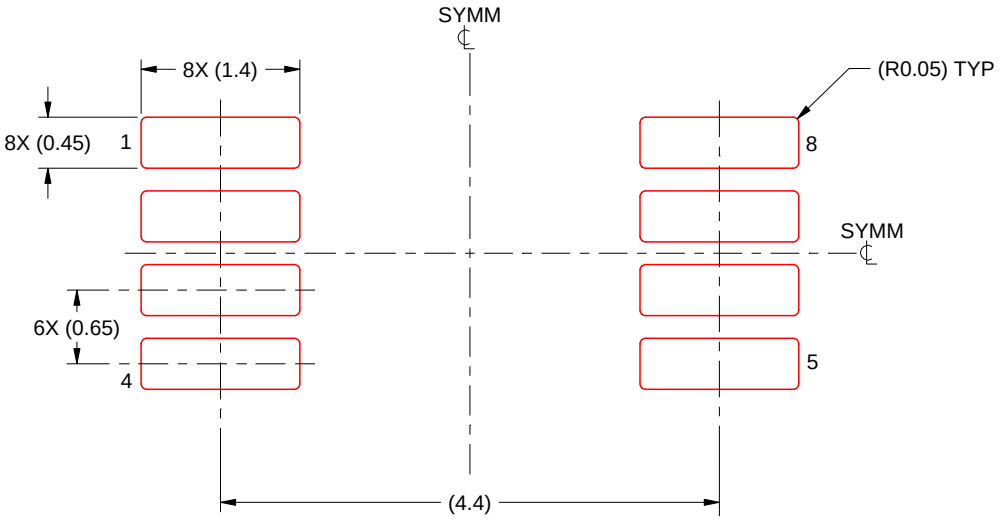


SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.



SOLDER PASTE EXAMPLE
SCALE: 15X

4214862/A 04/2023

NOTES: (continued)

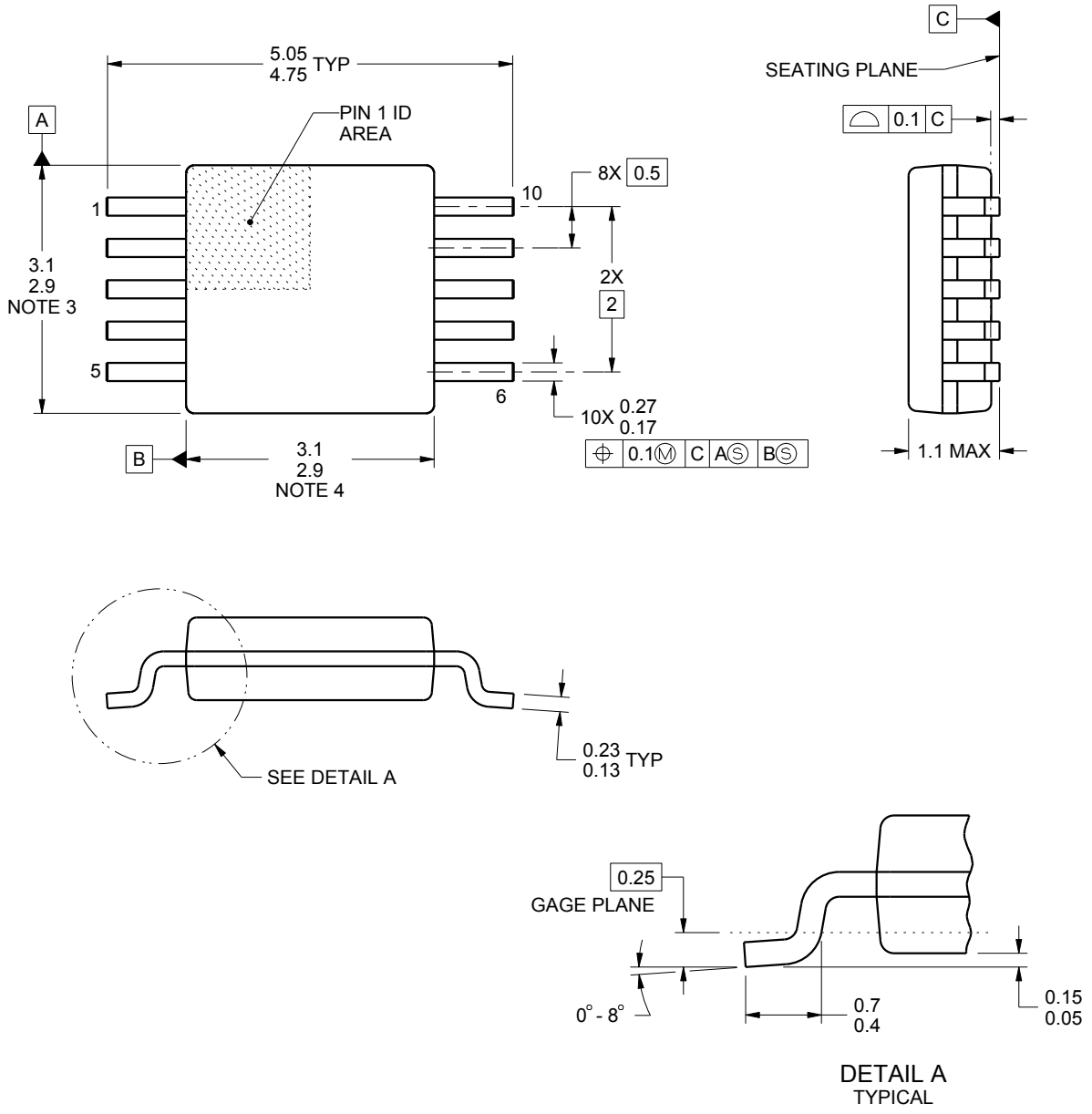
11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

PACKAGE OUTLINE

DGS0010A

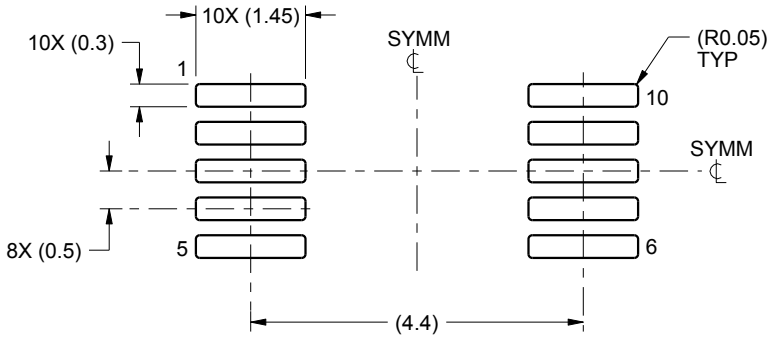
VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE

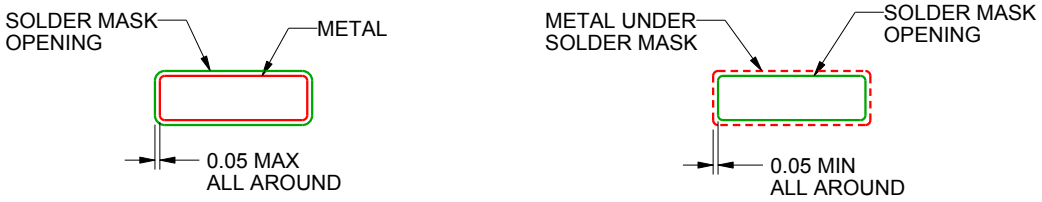


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187, variation BA.



LAND PATTERN EXAMPLE
SCALE:10X

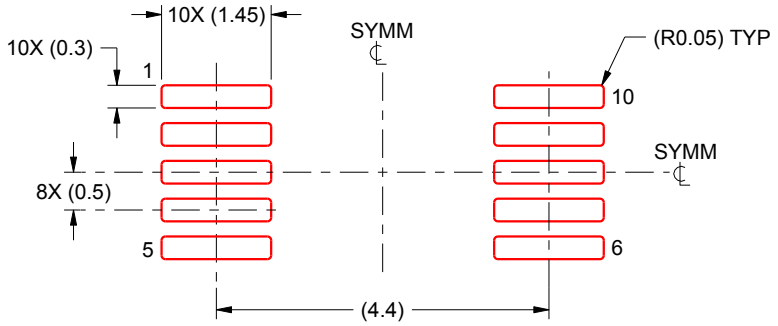


SOLDER MASK DETAILS
NOT TO SCALE

4221984/A 05/2015

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

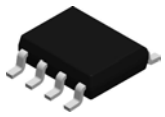


SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:10X

4221984/A 05/2015

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

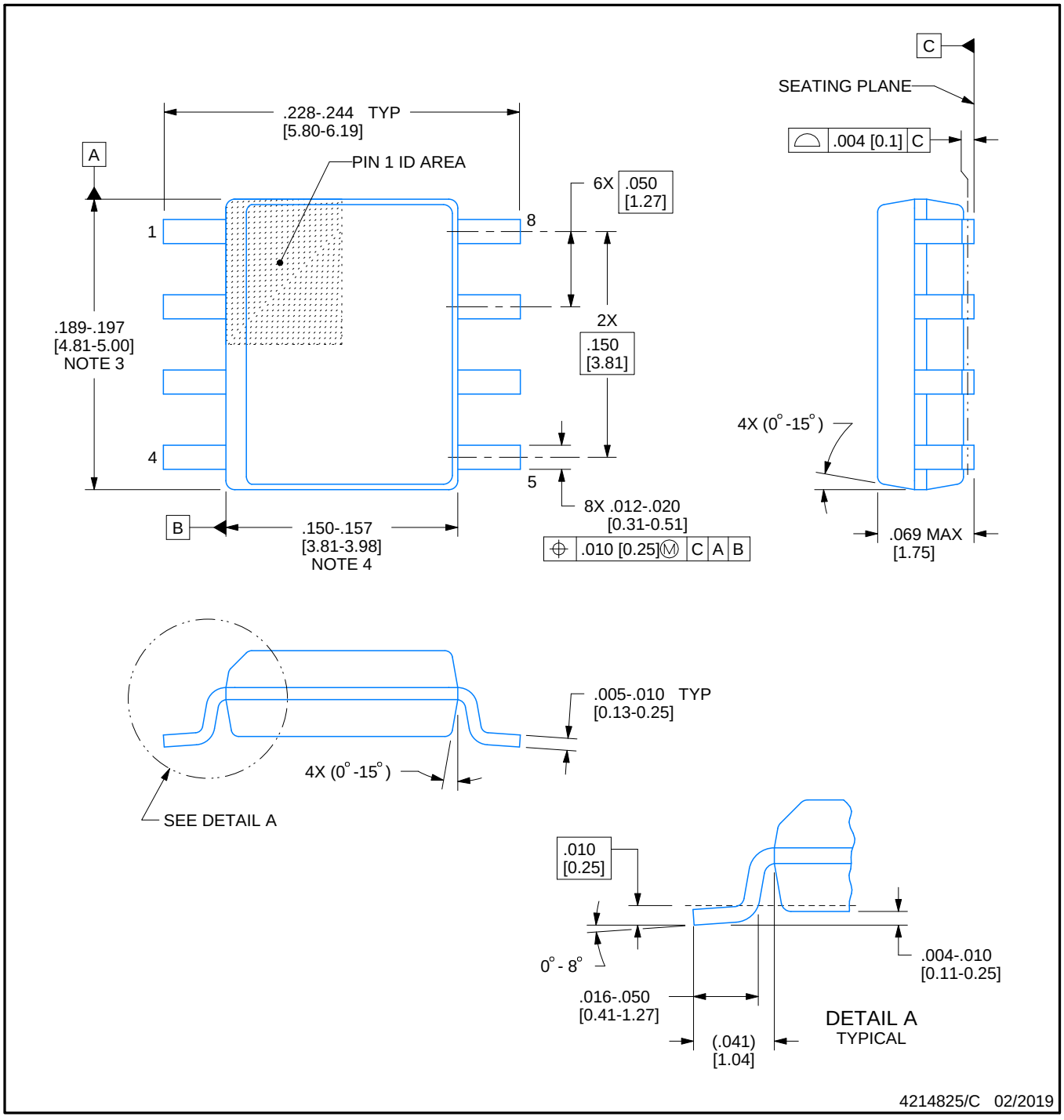


PACKAGE OUTLINE

D0008A

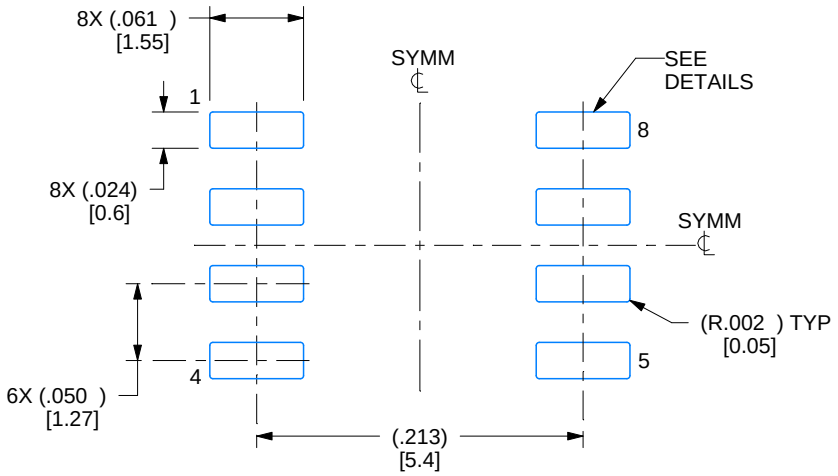
SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

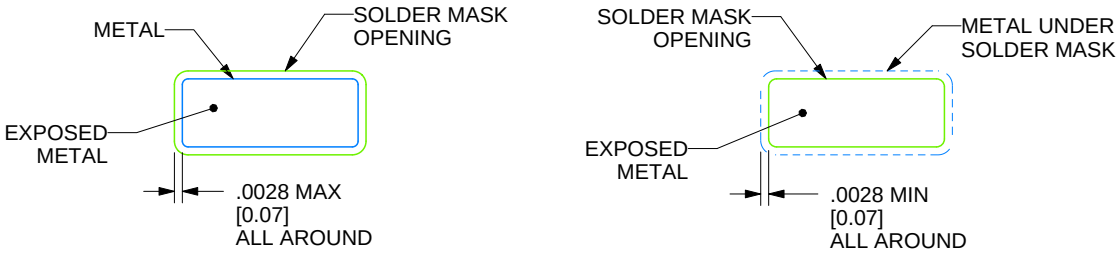


NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

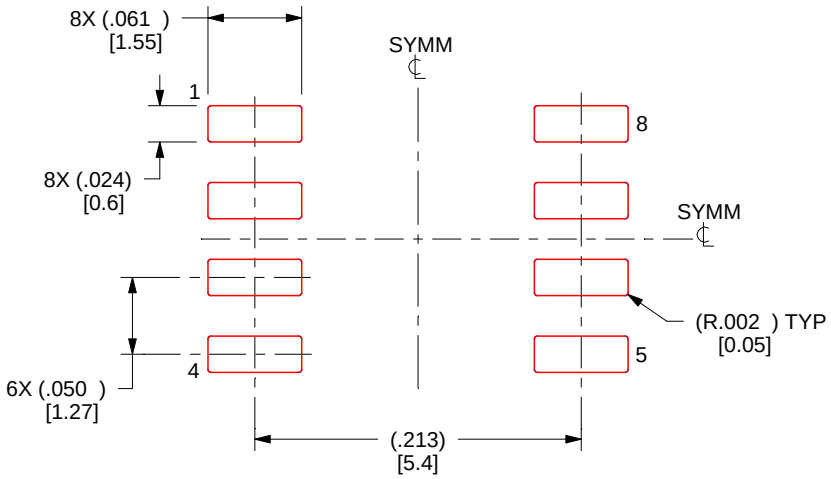
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

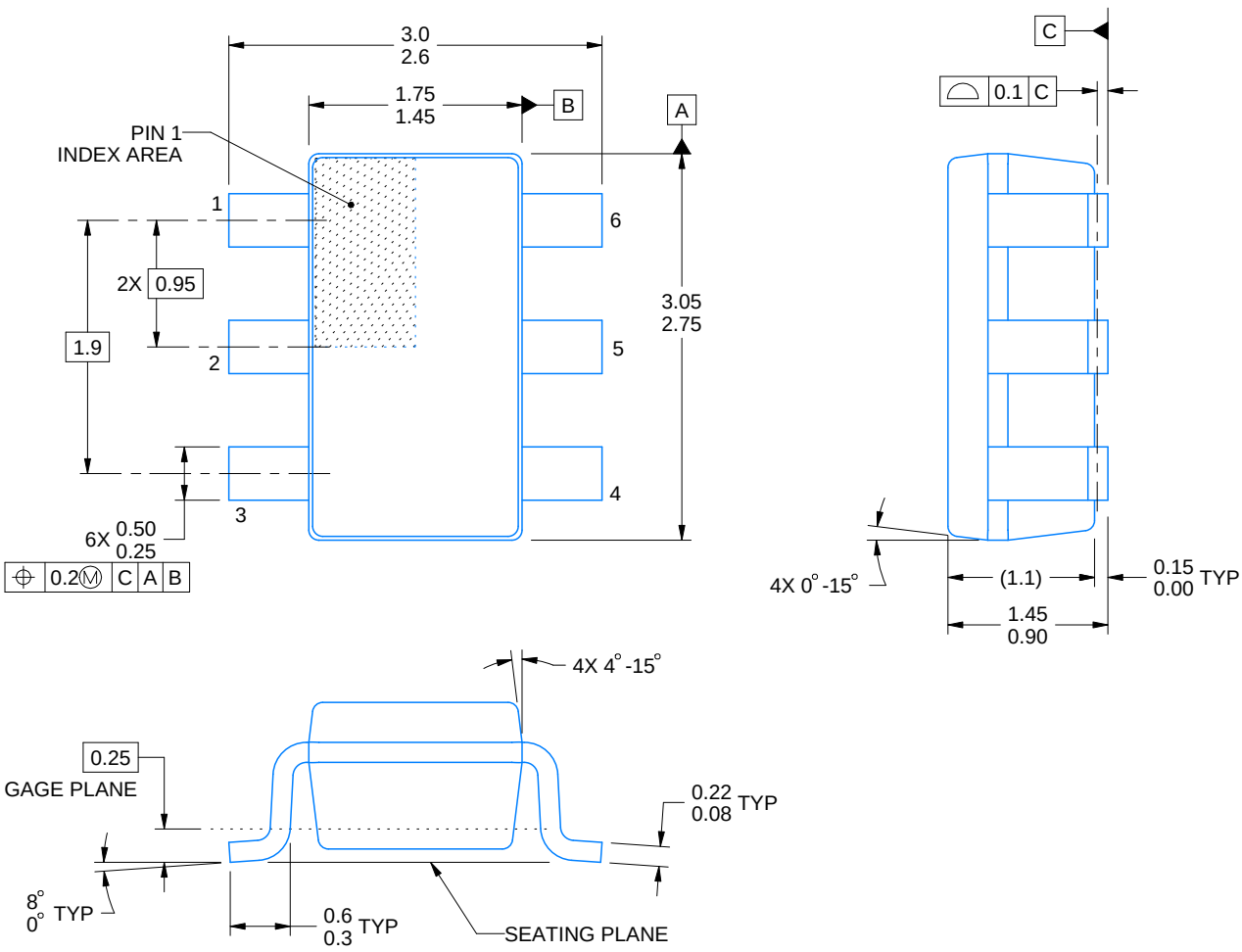
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

PACKAGE OUTLINE

DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



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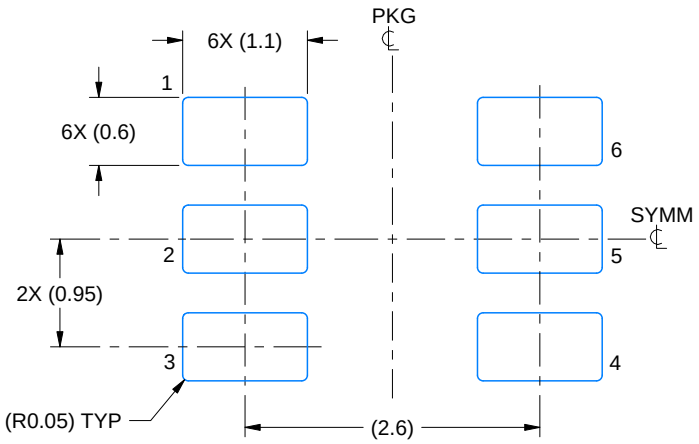
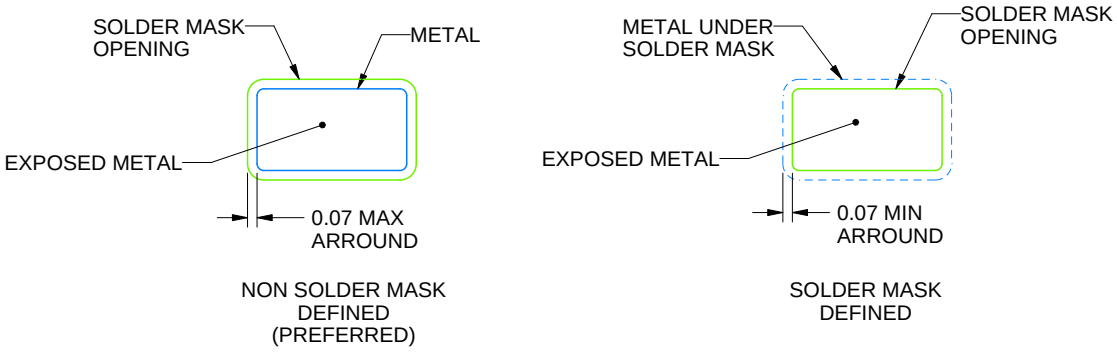
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.
4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
5. Refernce JEDEC MO-178.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

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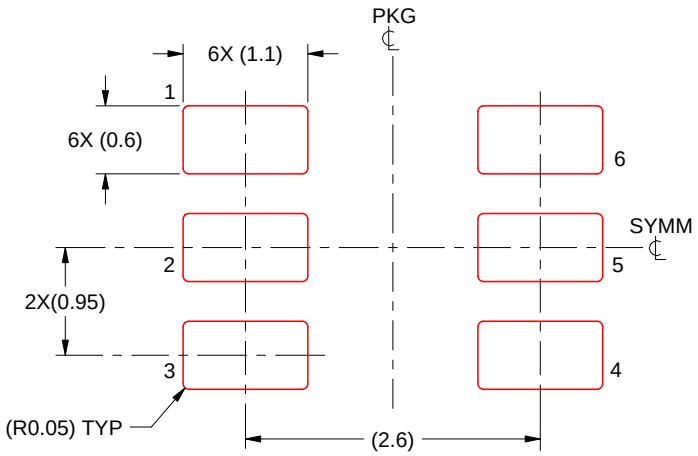
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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